October 17, 2008



LMH6714/ LMH6720/ LMH6722/ LMH6722Q Wideband Video Op Amp; Single, Single with Shutdown and Quad

General Description

LMH6714/LMH6720/LMH6722 The series combine National's VIP10[™] high speed complementary bipolar process with National's current feedback topology to produce a very high speed op amp. These amplifiers provide a 400MHz small signal bandwidth at a gain of +2V/V and a 1800V/µs slew rate while consuming only 5.6mA from ±5V supplies.

The LMH6714/LMH6720/LMH6722 series offer exceptional video performance with its 0.01% and 0.01° differential gain and phase errors for NTSC and PAL video signals while driving a back terminated 75Ω load. They also offer a flat gain response of 0.1dB to 120MHz. Additionally, they can deliver 70mA continuous output current. This level of performance makes them an ideal op amp for broadcast quality video systems.

The LMH6714/LMH6720/LMH6722's small packages (SOIC, SOT23 and LLP), low power requirement, low noise and distortion allow the LMH6714/LMH6720/LMH6722 to serve portable RF applications. The high impedance state during shutdown makes the LMH6720 suitable for use in multiplexing multiple high speed signals onto a shared transmission line. The LMH6720 is also ideal for portable applications where current draw can be reduced with the shutdown function.

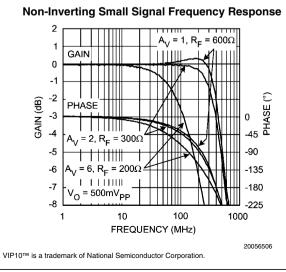
Features

- $400MHz (A_V = +2V/V, V_{OUT} = 500mV_{PP}) 3dB BW$
- 250MHz ($A_V = +2V/V$, $V_{OUT} = 2V_{PP}$) -3dB BW
- 0.1dB gain flatness to 120MHz
- Low power: 5.6mA
- TTL compatible shutdown pin (LMH6720)
- Very low diff. gain, phase: 0.01%, 0.01° (LMH6714)
- --58 HD2/ -70 HD3 at 20MHz
- Fast slew rate: 1800V/µs -
- Low shutdown current: 500uA (LMH6720)
- 11ns turn on time (LMH6720)
 - 7ns shutdown time (LMH6720)
 - Unity gain stable
- Improved replacement for CLC400,401,402,404,406 and 446 (LMH6714)
- Improved replacement for CLC405 (LMH6720)
- Improved replacement for CLC415 (LMH6722)
- LMH6722QSD is AEC-Q100 grade 1 gualified and is manufactured on an automotive grade flow

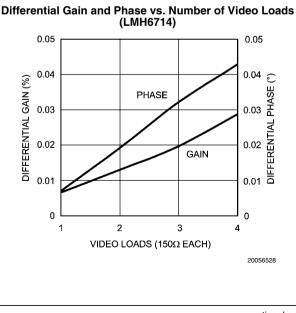
Applications

- HDTV, NTSC & PAL video systems
- Video switching and distribution
- Wideband active filters -
- Cable drivers
- High speed multiplexer (LMH6720)
- Programmable gain amplifier (LMH6720)
- Automotive (LMH6722)

Typical Performance







Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

ESD Tolerance (Note 4)	
Human Body Model	2000V
Machine Model	200V
V _{cc}	±6.75V
I _{OUT}	(Note 3)
Common Mode Input Voltage	$\pm V_{CC}$
Differential Input Voltage	2.2V
Maximum Junction Temperature	+150°C
Storage Temperature Range	–65°C to +150°C
Lead Temperature (soldering 10 sec)	+300°C

Operating Ratings (Note 1)

Thermal Resistance	
Package	(θ_{JA})
5-Pin SOT23	232°C/W
6-Pin SOT23	198°C/W
8-Pin SOIC	145°C/W
14-Pin SOIC	130°C/W
14-Pin TSSOP	160°C/W
14-Pin LLP	46°C/W
Operating Temperature	–40°C to 85°C
Operating Temperature LLP	–40°C to 125°C
Supply Voltage Range	8V (±4V) to 12.5V (±6.25V)

Electrical Characteristics

Unless specified, $A_V = +2$, $R_F = 300\Omega$: $V_{CC} = \pm 5V$, $R_L = 100\Omega$, LMH6714/LMH6720/LMH6722. **Boldface** limits apply at temperature extremes.

Symbol	Parameter	Conditions	Min (Note 7)	Typ (Note 6)	Max (Note 7)	Units
Frequen	cy Domain Response	1		(()	
SSBW	-3dB Bandwidth	$V_{OUT} = 0.5 V_{PP}$	345	400		MHz
LSBW	-3dB Bandwidth	V _{OUT} = 2.0V _{PP}	200	250		MHz
LSBW	-3dB Bandwidth, LMH6722 TSSOP package only	$V_{OUT} = 2.0 V_{PP}$	170	250		MHz
	Gain Flatness	$V_{OUT} = 2V_{PP}$				
GFP	Peaking	DC to 120MHz		0.1		dB
GFR	Rolloff	DC to 120MHz		0.1		dB
LPD	Linear Phase Deviation	DC to 120MHz		0.5		deg
DG	Differential Gain	R _L = 150Ω, 4.43MHz (LMH6714)		0.01		%
DG	Differential Gain	R _L = 150Ω, 4.43MHz (LMH6720)		0.02		%
DP	Differential Phase	R _L = 150Ω, 4.43MHz		0.01		deg
Time Do	main Response	1 -	Į	Į		
TRS	Rise and Fall Time	.5V Step		1.5		ns
TRL		2V Step		2.6		ns
t _s	Settling Time to 0.05%	2V Step		12		ns
SR	Slew Rate	6V Step	1200	1800		V/µs
Distortio	n and Noise Response			-		
HD2	2nd Harmonic Distortion	2V _{PP} , 20MHz		-58		dBc
HD3	3rd Harmonic Distortion	2V _{PP} , 20MHz		-70		dBc
IMD	3rd Order Intermodulation Products	10MHz, P _{OUT} = 0dBm		-78		dBc
	Equivalent Input Noise					
VN	Non-Inverting Voltage	>1MHz		3.4		nV/√H:
NICN	Inverting Current	>1MHz		10		pA/√H
ICN	Non-Inverting Current	>1MHz		1.2		pA/√H
Static, D	C Performance	1	I	I	L	· ·
V _{IO} Input Offset Voltage		±0.2	±6 ±8	mV		
DVIO	Average Drift			8		µV/°C

Symbol	Parameter	Cond	itions	Min (Note 7)	Typ (Note 6)	Max (Note 7)	Units
I _{BN}	Input Bias Current	Non-Inverting			±1	±10 ± 15	μA
DIBN	Average Drift				4		nA/°C
I _{BI}	Input Bias Current	Inverting			-4	±12 ±20	μA
DIBI	Average Drift				41		nA/°C
PSRR	Power Supply Rejection Ratio	DC		48 47	58		dB
CMRR	Common Mode Rejection Ratio	DC		48 45	54		dB
I _{CC}	Supply Current	$R_L = \infty$	LMH6714 LMH6720	4.5 3	5.6	7.5 8	
			LMH6722	18 15	22.5	30 32	mA
I _{CCI}	Supply Current During Shutdown	LMH6720			500	670	μA
Miscellar	neous Performance			•			
R _{IN}	Input Resistance	Non-Inverting			2		MΩ
C _{IN}	Input Capacitance	Non-Inverting			1.0		pF
R _{OUT}	Output Resistance	Closed Loop			0.06		Ω
V _{OUT}	Output Voltage Range	$R_L = \infty$		±3.5 ±3.4	±3.9		v
		R _L = 100Ω		±3.6 ±3.4	±3.8		v
CMIR	Input Voltage Range	Common Mode			±2.2		V
I _{OUT}	Output Current (Note 3)	V _{IN} = 0V, Max Linear Current		50	70		mA
OFFMA X	Voltage for Shutdown	LMH6720				0.8	V
ONMIN	Voltage for Turn On	LMH6720		2.0			V
IIH	Current Turn On	LMH6720, <u>SD</u> = 2.0V		-20 - 30	2	20 30	μA
IIL	Current Shutdown	LMH6720, <u>SD</u> = .8V		-600	-400	-100	μA
IOZ	R _{OUT} Shutdown	LMH6720, <u>SD</u> = .8V		0.2	1.8		MΩ
t _{on}	Turn on Time	LMH6720			11		ns
t _{off}	Turn off Time	LMH6720			7		ns

LMH6714/ LMH6720/ LMH6722/ LMH6722Q

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not guaranteed. For guaranteed specifications, see the Electrical Characteristics tables.

Note 2: Electrical Table values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in very limited self-heating of the device such that T_J = T_A. No guarantee of parametric performance is indicated in the electrical tables under conditions of internal self heating where T_J > T_A. See Applications Section for information on temperature derating of this device." Min/Max ratings are based on product characterization and simulation. Individual parameters are tested as noted.

Note 3: The maximum output current (I_{OUT}) is determined by device power dissipation limitations. See the Power Dissipation section of the Application Division for more details.

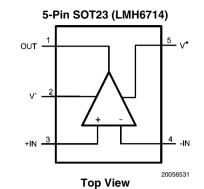
Note 4: Human Body Model, applicable std. MIL-STD-883, Method 3015.7. Machine Model, applicable std. JESD22-A115-A (ESD MM std. of JEDEC) Field-Induced Charge-Device Model, applicable std. JESD22-C101-C (ESD FICDM std. of JEDEC).

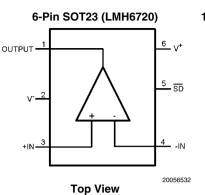
Note 5: The shutdown pin is designed to work between 0 and V_{CC} with split supplies (V_{CC} = -V_{EE}). With single supplies (V_{EE} = ground) the shutdown pin should not be taken below V_{CC}/2.

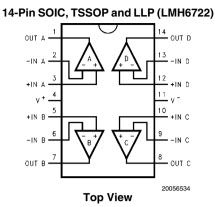
Note 6: Typical values represent the most likely parametric norm at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration. The typical values are not tested and are not guaranteed on shipped production material.

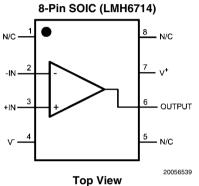
Note 7: All limits are guaranteed by testing, design, or statistical analysis.

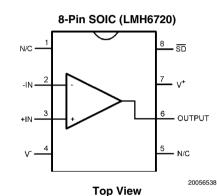
Connection Diagrams









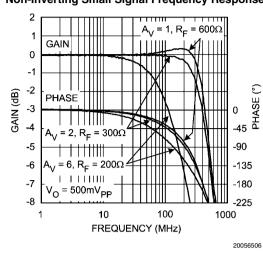


Ordering Information

Package	Part Number	Package Marking	Transport Media	NSC Drawing	Features	
5-Pin SOT23 -	LMH6714MF	A05A	1k Units Tape and Reel			
	LMH6714MFX	A95A	3k Units Tape and Reel	MF05A		
8-Pin SOIC	LMH6714MA		95 Units / Rail	14004		
8-PIN SOIC	LMH6714MAX	LMH6714MA	2.5k Units Tape and Reel	M08A		
6-Pin SOT23	LMH6720MF	A96A	1k Units Tape and Reel			
6-PIN 50123	LMH6720MFX	АубА	3k Units Tape and Reel	MF06A		
	LMH6720MA		95 Units / Rail	M08A		
8-Pin SOIC	LMH6720MAX	LMH6720MA	2.5k Units Tape and Reel			
	LMH6722MA		55 Units / Rail	NA1 4 A		
14-Pin SOIC	LMH6722MAX	LMH6722MA	2.5k Units Tape and Reel	M14A		
14–Pin	LMH6722MT		94 Units / Rail	MTO14		
TSSOP	LMH6722MTX	LMH6722MT	2.5k Units Tape and Reel	MTC14		
	LMH6722SD	1.0700	1k Units Tape and Reel		AEC-Q100 Grade 1	
	LMH6722SDX	L6722	4.5k Units Tape and Reel	004144	qualified.	
14-Pin LLP	LMH6722QSD		1k Units Tape and Reel	SDA14A	Automotive Grade	
Γ	LMH6722QSDX	L6722Q	4.5k Units Tape and Reel		Production Flow**	

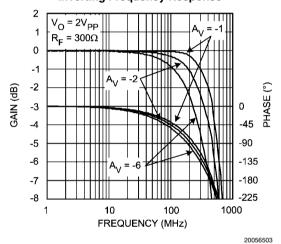
**Automotive Grade (Q) product incorporates enhanced manufacturing and support processes for the automotive market, including defect detection methodologies. Reliability qualification is compliant with the requirements and temperature grades defined in the AEC-Q100 standard. Automotive grade products are identified with the letter Q. For more information go to http://www.national.com/automotive.

Typical Performance Characteristics $(V^+ = +5V, V^- = -5V, A_V = 2, R_F = 300\Omega, R_L = 100\Omega$ Unless Specified).

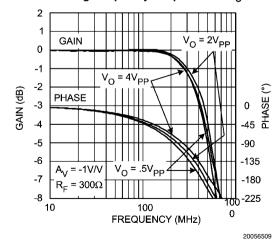


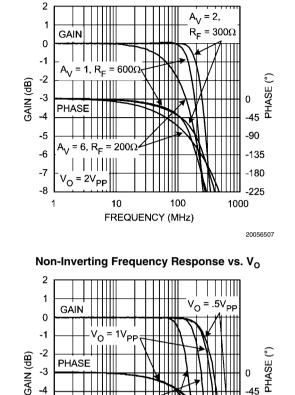
Non-Inverting Small Signal Frequency Response

Inverting Frequency Response



Inverting Frequency Response vs. Vo





= 2\// -8 -225 1 10 100 1000 FREQUENCY (MHz) 20056508 Harmonic Distortion vs. Frequency

-45

-90

135

-180

-4

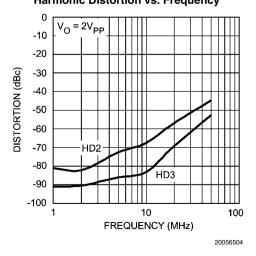
-5

-6

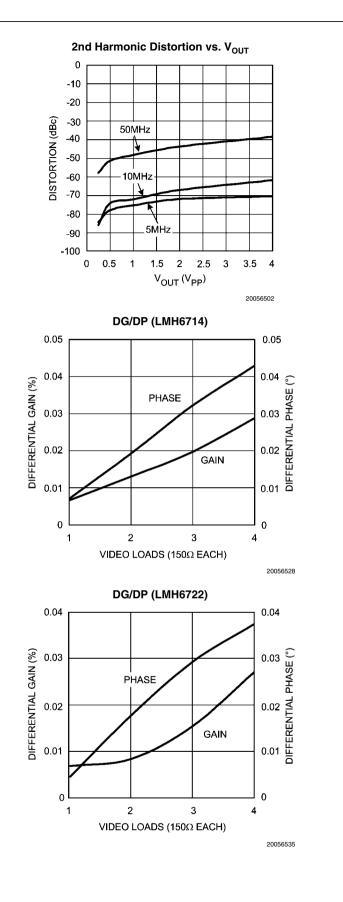
-7

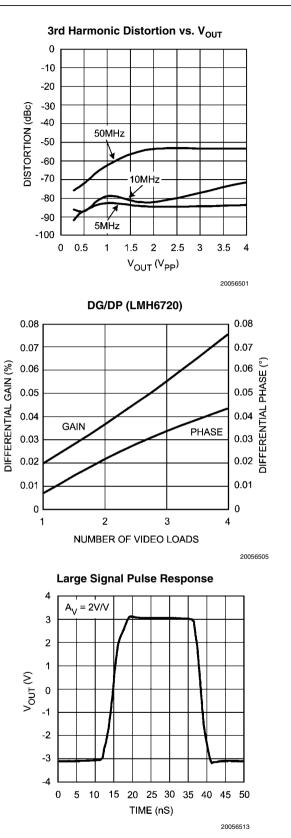
 $V_0 = 2V_P$

= 300Ω R,

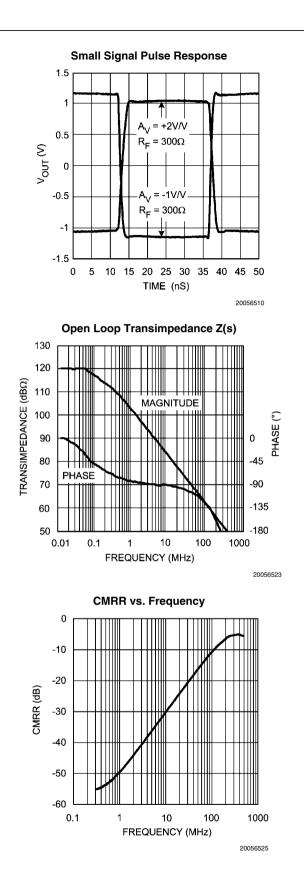


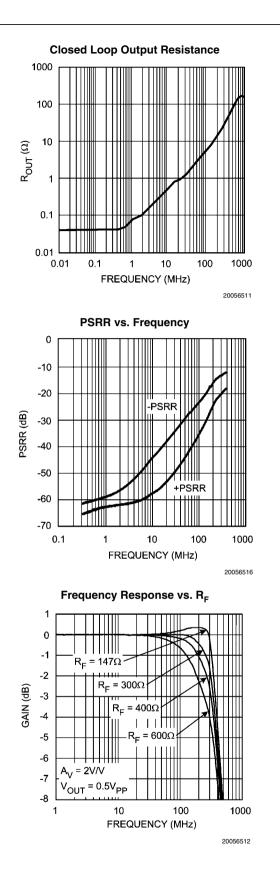
Non-Inverting Large Signal Frequency Response

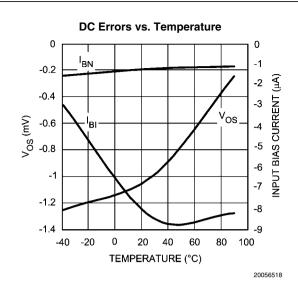




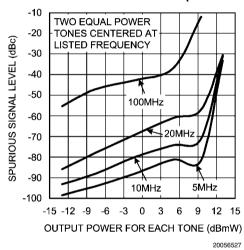


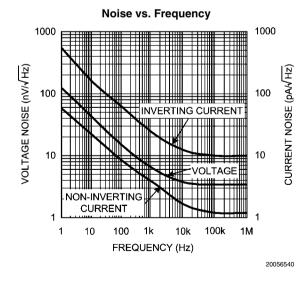


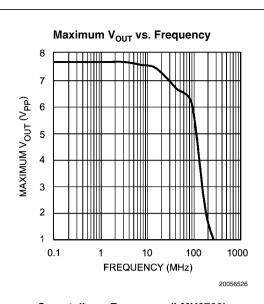




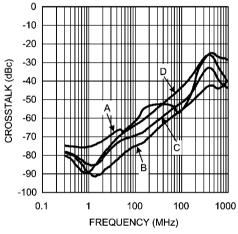
3rd Order Intermodulation vs. Output Power







Crosstalk vs. Frequency (LMH6722) for each channel with all others active



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Application Section FEEDBACK RESISTOR SELECTION

One of the key benefits of a current feedback operational amplifier is the ability to maintain optimum frequency response independent of gain by using appropriate values for the feedback resistor (R_F). The Electrical Characteristics and Typical Performance plots specify an R_F of 300 Ω , a gain of +2V/V and ±5V power supplies (unless otherwise specified). Generally, lowering R_F from it's recommended value will peak the frequency response and extend the bandwidth while increasing the value of R_F will cause the frequency response to roll off faster. Reducing the value of R_F too far below it's recommended value will cause overshoot, ringing and, eventually, oscillation.

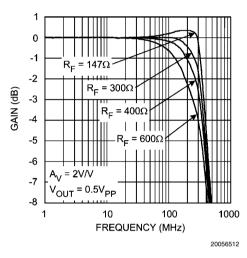


FIGURE 1. Frequency Response vs. R_F

The plot labeled "Frequency Response vs. $R_{\rm F}$ " shows the LMH6714/LMH6720/LMH6722's frequency response as $R_{\rm F}$ is varied ($R_{\rm L}$ = 100 Ω , $A_{\rm V}$ = +2). This plot shows that an $R_{\rm F}$ of 147 Ω results in peaking. An $R_{\rm F}$ of 300 Ω gives near maximal bandwidth and gain flatness with good stability. An $R_{\rm F}$ of 400 Ω gives excellent stability with only a small bandwidth penalty. Since all applications are slightly different it is worth some experimentation to find the optimal $R_{\rm F}$ for a given circuit. Note that it is not possible to use a current feedback amplifier with the output shorted directly to the inverting input. The buffer configuration of the LMH6714/LMH6720/LMH6722 requires a 600 Ω feedback resistor for stable operation.

For more information see Application Note OA-13 which describes the relationship between R_F and closed-loop frequency response for current feedback operational amplifiers. The value for the inverting input impedance for the LMH6714/LMH6720/LMH6722 is approximately 180 Ω . The LMH6714/LMH6720/LMH6722 is designed for optimum performance at gains of +1 to +6 V/V and -1 to -5V/V. When using gains of ±7V/V or more the low values of R_G required will make inverting input impedances very low.

When configuring the LMH6714/LMH6720/LMH6722 for gains other than +2V/V, it is usually necessary to adjust the value of the feedback resistor. The two plots labeled " R_F vs. Non-inverting Gain" and " R_F vs. Inverting Gain" provide recommended feedback resistor values for a number of gain selections.

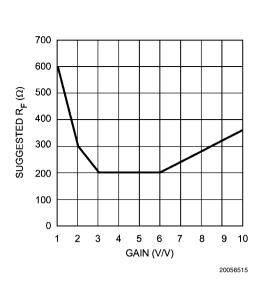


FIGURE 2. R_F vs. Non-Inverting Gain

In the "R_F vs. Non-Inverting Gain" and the "R_F vs. Inverting Gain" charts the recommended value of R_F is depicted by the solid line, which starts high, decreases to 200 Ω and begins increasing again. The reason that a higher R_F is required at higher gains is the need to keep R_G from decreasing too far below the output impedance of the input buffer. For the LMH6714/LMH6720/LMH6722 the output resistance of the input buffer is approximately 180 Ω and 50 Ω is a practical lower limit for R_G. Due to the limitations on R_G the LMH6714/LMH6720/LMH6722 begins to operate in a gain bandwidth limited fashion for gains of ±5V/V or greater.

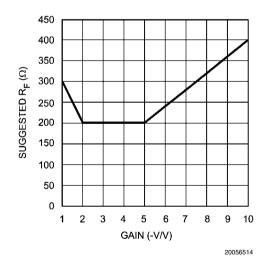
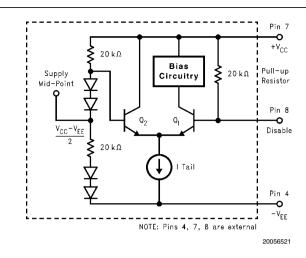


FIGURE 3. R_F vs. Inverting Gain

ACTIVE FILTERS

When using any current feedback Operational Amplifier as an active filter it is important to be very careful when using reactive components in the feedback loop. Anything that reduces the impedance of the negative feedback, especially at higher frequencies, will almost certainly cause stability problems. Likewise capacitance on the inverting input needs to be avoided. See Application Notes OA-7 and OA-26 for more information on Active Filter applications for Current Feedback Op Amps.





ENABLE/DISABLE OPERATION USING ±5V SUPPLIES (LMH6720 ONLY)

The LMH6720 has a TTL logic compatible disable function. Apply a logic low (<.8V) to the DS pin and the LMH6720 is disabled. Apply a logic high (>2.0V), or let the pin float and the LMH6720 is enabled. Voltage, not current, at the Disable pin determines the enable/disable state. Care must be exercised to prevent the disable pin voltage from going more than . 8V below the midpoint of the supply voltages (0V with split supplies, $V_{CC}/2$ with single supplies) doing so could cause transistor Q1 to Zener resulting in damage to the disable circuit. The core amplifier is unaffected by this, but disable operation could become slower as a result.

Disabled, the LMH6720 inputs and output become high impedances. While disabled the LMH6720 quiescent current is approximately 500µA. Because of the pull up resistor on the disable circuit the I_{CC} and I_{EE} currents are not balanced in the disabled state. The positive supply current (I_{CC}) is approximately 500µA while the negative supply current (I_{EE}) is only 200µA. The remaining I_{EE} current of 300µA flows through the disable pin.

The disable function can be used to create analog switches or multiplexers. Implement a single analog switch with one LMH6720 positioned between an input and output. Create an analog multiplexer with several LMH6720's. The LMH6720 is at it's best at a gain of 1 for multiplexer applications because there is no R_G to shunt signals to ground.

DISABLE LIMITATIONS (LMH6720 ONLY)

The feedback Resistor (R_F) limits off isolation in inverting gain configurations. During shutdown the impedance of the LMH6720 inputs and output become very high (>1M\Omega), however R_F and R_G are the dominant factor for effective output impedance.

Do not apply voltages greater than $+V_{CC}$ or less than 0V ($V_{CC}/2$ single supply) to the disable pin. The input ESD diodes will also conduct if the signal leakage through the feedback resistors brings the inverting input near either supply rail.

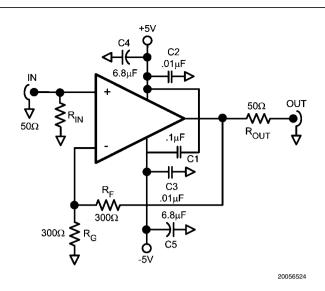


FIGURE 5. Typical Application with Suggested Supply Bypassing

LAYOUT CONSIDERATIONS

Whenever questions about layout arise, use the evaluation board as a guide. The following Evaluation boards are available with sample parts:

SOT	CLC730216
SOIC	CLC730227
SOT	CLC730216
SOIC	CLC730227
SOIC	CLC730231
	SOIC SOT SOIC

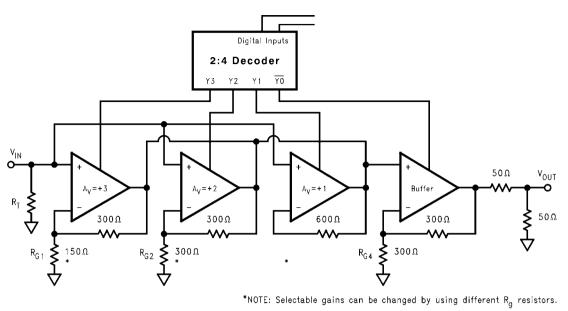
To reduce parasitic capacitances, the ground plane should be removed near the input and output pins. To reduce series inductance, trace lengths of components in the feedback loop should be minimized. For long signal paths controlled impedance lines should be used, along with impedance matching at both ends.

Bypass capacitors should be placed as close to the device as possible. Bypass capacitors from each rail to ground are applied in pairs. The larger electrolytic bypass capacitors can be located anywhere on the board, the smaller ceramic capacitors should be placed as close to the device as possible. In addition *Figure 2* shows a capacitor (C1) across the supplies with no connection to ground. This capacitor is optional, however it is required for best 2nd Harmonic suppression. If this capacitor is omitted C2 and C3 should be increased to .1 μ F each.

VIDEO PERFORMANCE

The LMH6714/LMH6720/LMH6722 has been designed to provide excellent performance with both PAL and NTSC composite video signals. Performance degrades as the loading is increased, therefore best performance will be obtained with back terminated loads. The back termination reduces reflections from the transmission line and effectively masks capacitance from the amplifier output stage. While all parts offer excellent video performance the LMH6714 and LMH6722 are slightly better than the LMH6720.

WIDE BAND DIGITAL PROGRAMMABLE GAIN AMPLIFIER (LMH6720 ONLY)



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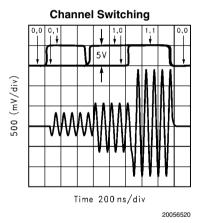


FIGURE 7. PGA Output

As shown in *Figure 6* and *Figure 7* the LMH6720 can be used to construct a digitally controlled programmable gain amplifier. Each amplifier is configured to provide a digitally selectable gain. To provide for accurate gain settings, 1% or **AMPLITUDE EQUALIZATION**

Sending signals over coaxial cable greater than 50 meters in length will attenuate high frequency signal components much more than lower frequency components. An equalizer can be made to pre emphasize the higher frequency components so that the final signal has less distortion. This process can be done at either end of the cable. The circuit in *Figure 8* shows a receiver with some additional components in the feedback loop to equalize the incoming signal. The RC networks peak the signal at higher frequencies. This peaking is a piecewise linear approximation of the inverse of the frequency response of the coaxial cable. *Figure 9* shows the effect of this equalization on a digital signal that has passed through 150 meters of coaxial cable. *Figure 10* shows a Bode plot of the frequency

better tolerance is recommended on the feedback and gain resistors. The gain provided by each digital code is arbitrary through selection of the feedback and gain resistor values.

response of the circuit in *Figure 8* along with equations needed to design the pole and zero frequencies. *Figure 11* shows a network analyzer plot of an LMH6714/LMH6720/LMH6722 with the following component values:

R _G = 309Ω
R1 = 450Ω
C1 = 470pF
R2 = 91Ω

C2 = 68pF

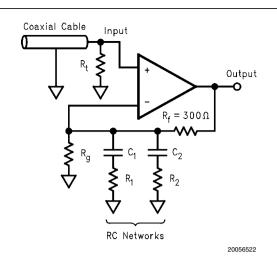


FIGURE 8. Equalizer Circuit Schematic

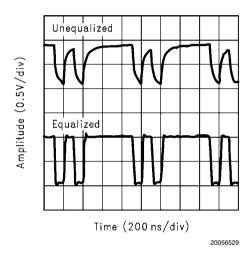
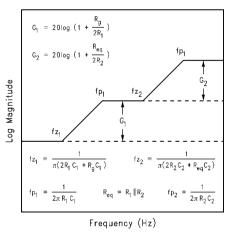


FIGURE 9. Digital Signal without and with Equalization



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FIGURE 10. Design Equations

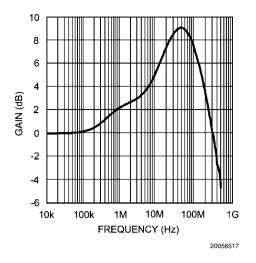


FIGURE 11. Equalizer Frequency Response

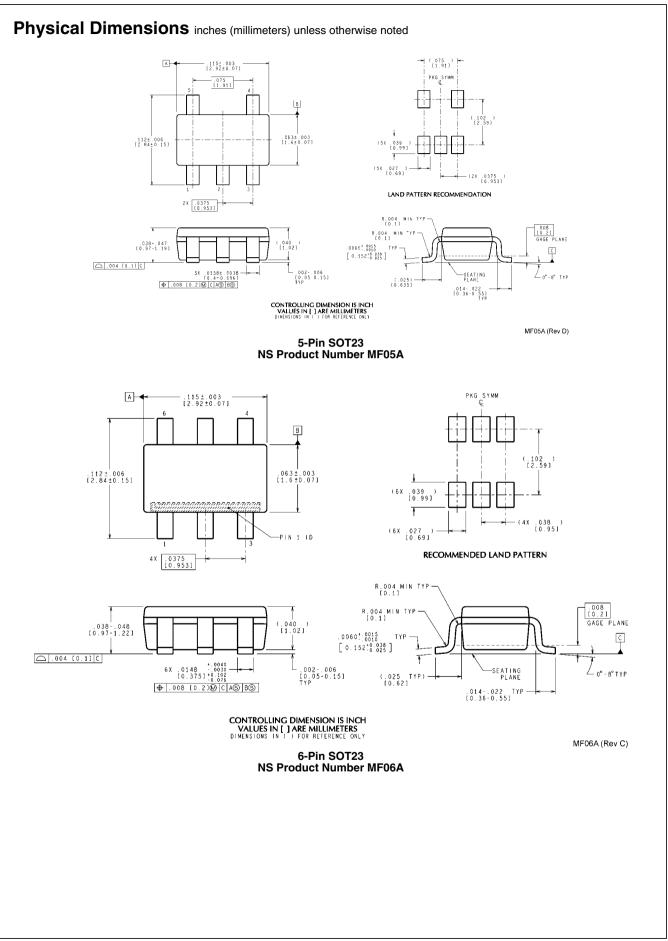
POWER DISSIPATION

Follow these steps to determine the Maximum power dissipation for the LMH6714/LMH6720/LMH6722:

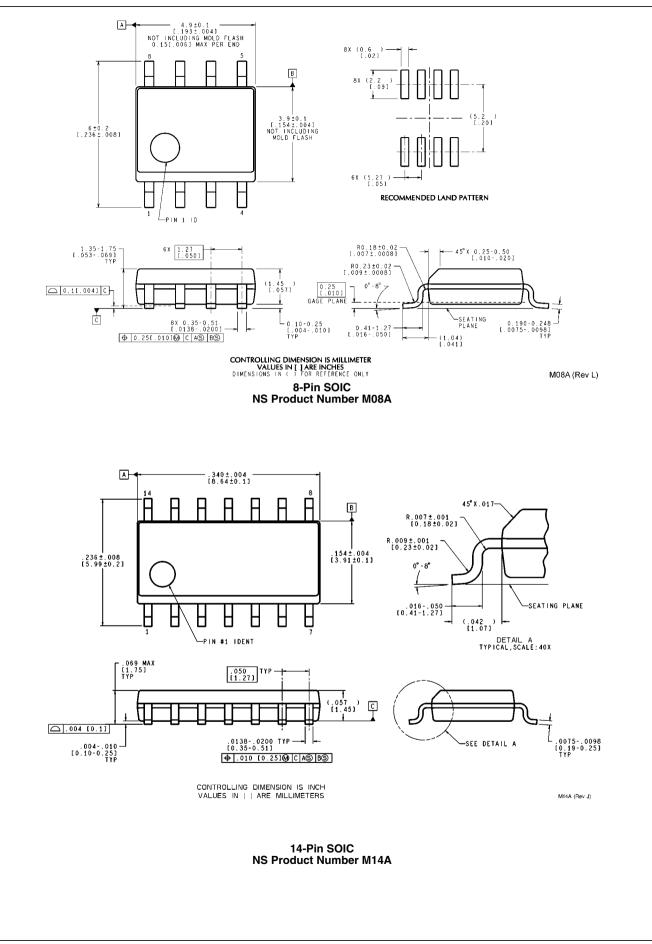
- 1. Calculate the quiescent (no load) power: $P_{AMP} = I_{CC}$ ($V_{CC} V_{EE}$)
- **2.** Calculate the RMS power at the output stage: P_{OUT} (RMS) = ((V_{CC} V_{OUT} (RMS)) * I_{OUT} (RMS)), where V_{OUT} and I_{OUT} are the voltage and current across the external load.
- **3.** Calculate the total RMS power: $P_T = P_{AMP} + P_{OUT}$

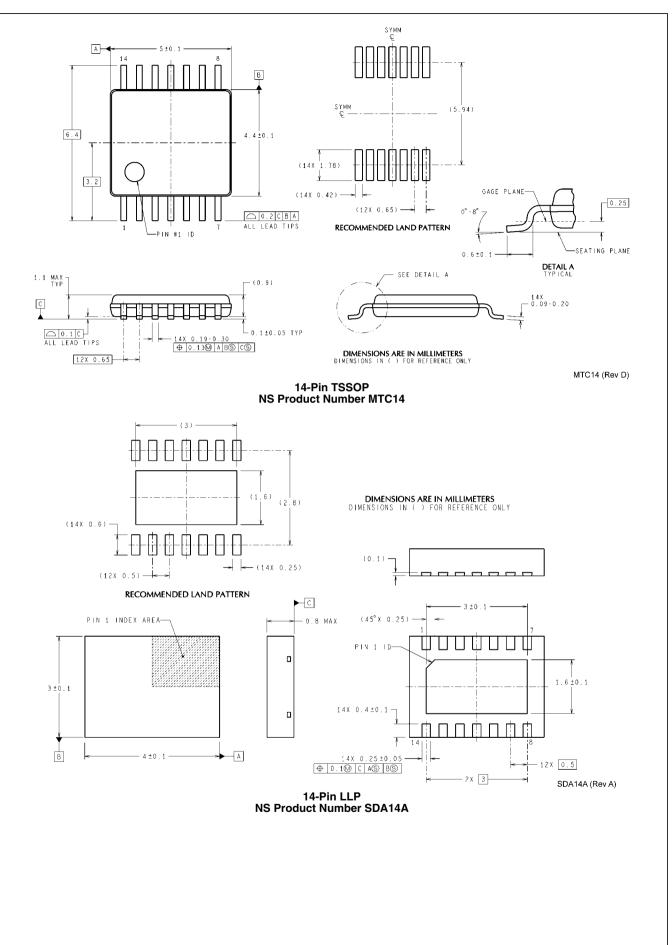
The maximum power that the LMH6714/LMH6720/LMH6722, package can dissipate at a given temperature can be derived with the following equation:

 $\begin{array}{l} P_{MAX} = (150^{\circ} - T_{A}) / \ \theta_{JA}, \ where \ T_{A} = Ambient \ temperature \ (^{\circ} \ C) \ and \ \theta_{JA} = Thermal \ resistance, \ from \ junction \ to \ ambient, \ for \ a \ given \ package \ (^{\circ}C/W). \ For \ the \ SOIC \ package \ \theta_{JA} \ is \ 148^{\circ}C/W, \ for \ the \ SOT \ it \ is \ 250^{\circ}C/W. \end{array}$



LMH6714/ LMH6720/ LMH6722/ LMH6722Q





LMH6714/ LMH6720/ LMH6722/ LMH6722Q

Notes

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